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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

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Complete if Known

Application Number

Filing Date

February 18, 2004

First Named Inventor

Wu, Koucheng

Art Unit

Examiner Name

Attorney Docket Number

KWU002

Sheet

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of

1

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	1	D. Burnett, D. Shum, and K. Baker, "An Advanved Flash Memory Technology on SOI", IEDM Tech. Digest, pp. 983-986, 1998.	
	2	K. S. Kim, J. Y. Kim, J. W. Yoo, Y. B. Choi, M. K. Kim, B.Y. Nam, K. T. Park, S. T. Ahn, and O. H. Kwon, "A Novel Dual String NOR (DuSNOR) Memory Cell Technology Scalable to the 256 Mbit and 1 Gbit Flash Memories", IEDM Tech. Digest, pp. 263-266, 1995.	
	3	Y. Yamauchi, M. Yoshimi, S. Sato, H. Tabuchi, N. Takenaka, and K. Sakiyam, "A New Cell Structure for Sub-quarter Micron High Density Flash Memory", IEDM Tech. Digest, pp. 267-270, 1995.	
	4	S. Aritome, R. Shiota, R. Kirisawa, T. Endoh, R. Nakayama, K. Sakui, and F. Masuoka, "A Reliable Bi-polarity Write/Erase Technology in Flash EEPROMs", IEDM Tech. Digest, pp. 111-114, 1990.	

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U. S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
		US- 5,796,142	8/18/1998	Ruei-Ling Lin	
		US- 5,885,868	5/23/1999	Ruei-Ling Lin	
		US- 5,995,412	11/30/1999	Yoshiji Ohta	
		US- 6,226,198	5/1/2001	Hitoshi Miwa	
		US- 6,438,030 B1	8/20/2002	Chung-you Hu	
		US- 6,406,958	6/18/2002	M. Kato	
		US- 5,672,529	9/30/1997	M. Kato	
		US- 5,932,909	5/5/1997	M. Kato	
		US- 6,072,722	6/6/2000	Y. Hirano	
		US- 6,266,270	6/24/2001	H. Nobukata	
		US-			
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FOREIGN PATENT DOCUMENTS

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